## 2SB1417, 2SB1417A

### Silicon PNP epitaxial planar type

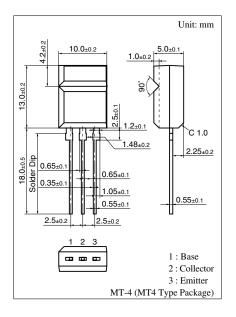
# For power amplification Complementary to 2SD2137 and 2SD2137A

#### ■ Features

- High forward current transfer ratio h<sub>FE</sub> which has satisfactory linearity
- ullet Low collector to emitter saturation voltage  $V_{CE(sat)}$
- Allowing automatic insertion with radial taping

#### ■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base	2SB1417	$V_{CBO}$	-60	V
voltage	2SB1417A		-80	
Collector to	2SB1417	$V_{CEO}$	-60	V
emitter voltage	2SB1417A		-80	
Emitter to base voltage		$V_{EBO}$	-6	V
Peak collector current		$I_{CP}$	-5	A
Collector current		$I_C$	-3	A
Collector power	$T_C = 25^{\circ}C$	$P_{C}$	15	W
dissipation	$T_a = 25^{\circ}C$		2.0	
Junction temperature		T <sub>j</sub>	150	°C
Storage temperature		$T_{stg}$	-55 to +150	°C



#### ■ Electrical Characteristics $T_C = 25$ °C

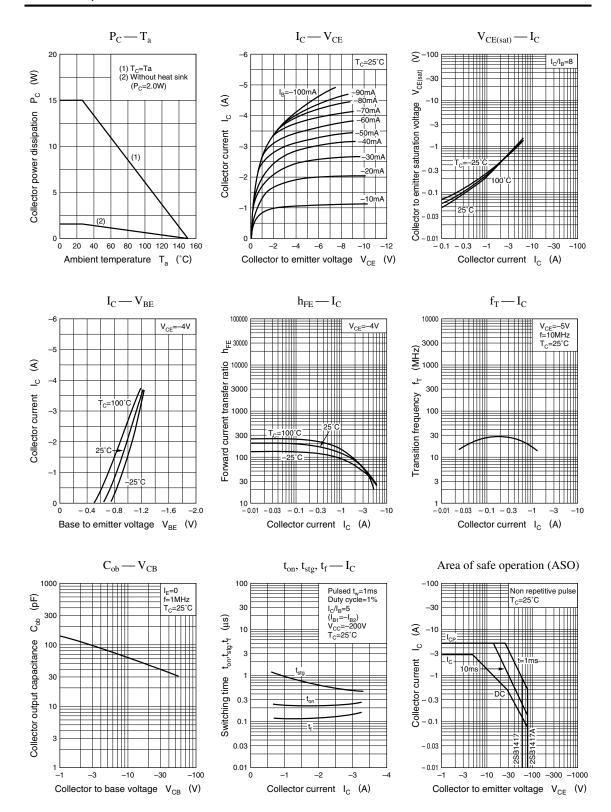
Paramete	r	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SB1417	I <sub>CES</sub>	$V_{CE} = -60 \text{ V}, V_{BE} = 0$			-100	μΑ
current	2SB1417A		$V_{CE} = -80 \text{ V}, V_{BE} = 0$			-100	
Collector cutoff	2SB1417	I <sub>CEO</sub>	$V_{CE} = -30 \text{ V}, I_{B} = 0$			-100	μΑ
current	2SB1417A		$V_{CE} = -60 \text{ V}, I_{B} = 0$			-100	
Emitter cutoff current		$I_{EBO}$	$V_{EB} = -6 \text{ V}, I_C = 0$			-100	μΑ
Collector to emitter	2SB1417	$V_{CEO}$	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-60			V
voltage	2SB1417A			-80			
Forward current transfer ratio		h <sub>FE1</sub> *	$V_{CE} = -4 \text{ V}, I_{C} = -1 \text{ A}$	70		250	
		h <sub>FE2</sub>	$V_{CE} = -4 \text{ V}, I_{C} = -3 \text{ A}$	10			
Base to emitter voltage	;	$V_{BE}$	$V_{CE} = -4 \text{ V}, I_C = -3 \text{ A}$			-1.8	V
Collector to emitter satu	ration voltage	V <sub>CE(sat)</sub>	$I_C = -3 \text{ A}, I_B = -0.375 \text{ A}$			-1.2	V
Transition frequency		$f_T$	$V_{CE} = -5 \text{ V}, I_C = -0.2 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time		t <sub>on</sub>	$I_C = -1 A$ , $I_{B1} = -0.1 A$ , $I_{B2} = 0.1 A$ ,		0.3		μs
Storage time		t <sub>stg</sub>	$V_{CC} = -50 \text{ V}$		1.0		μs
Fall time		$t_{\mathrm{f}}$			0.2		μs

Note) \*: Rank classification

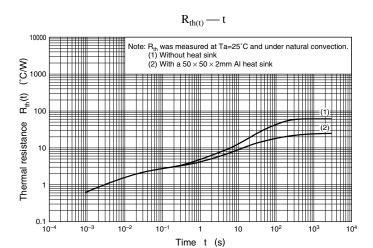
Rank	Q	Р		
h <sub>FE1</sub>	70 to 150	120 to 250		

Ordering can be made by the common rank (PQ rank  $h_{\text{FEI}}$  = 70 to 250) in the rank classification.

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